



# D8V0H1U2LP1610

### **Product Summary**

V <sub>BR (Min)</sub>	IPP (Max)	С <sub>Т (Тур)</sub>
8.2V	100A	700pF

# **Description and Applications**

This new generation TVS is designed to protect sensitive electronics from the damage due to ESD. The combination of small size and high ESD surge capability makes it ideal for use in:

- Cellular Handsets
- Portable Electronics
- Computers and Peripheral



Bottom View

### **8V VOLT UNI-DIRECTIONAL HIGH SURGE TVS DIODE**

## **Features and Benefits**

- Provides ESD Protection per IEC 61000-4-2 Standard: Air ±30kV, Contact ±30kV
- One Channel of ESD Protection
- Low Channel Input Capacitance
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)

## **Mechanical Data**

- Case: U-DFN1610-2 (Type B)
- Case Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: NiPdAu over Copper Leadframe. Solderable per MIL-STD-202, Method 208 @4
- Weight: 0.003 grams (Approximate)



**Device Schematic** 

# Ordering Information (Note 4)

Part Number	Compliance	Marking	Reel Size (inches)	Tape Width (mm)	Quantity per Reel
D8V0H1U2LP1610-7	Standard	2M	7	8	10,000/Tape & Reel

Notes: 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant.

2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.

3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

4. For packaging details, see https://www.diodes.com/design/support/packaging/diodes-packaging/.

# **Marking Information**

	2M	
•	YM	

2M = Product Type Marking Code YM = Date Code Marking Y = Year (ex: F = 2018) M = Month (ex: 9 = September) Bar Denotes Pin1 or Cathode side

Date Code Key	,
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Year	201	7	2018		2019	20	20	2021		2022	2	2023
Code	E		F		G	ł	4			J		K
Month	Jan	Feb	Mar	Apr	Мау	Jun	Jul	Aug	Sep	Oct	Nov	Dec
Code	1	2	3	4	5	6	7	8	9	0	N	D



# Maximum Ratings (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit	Condition
Peak Pulse Current	IPP	100	А	8/20µs (Note 7)
Peak Pulse Power Dissipation	P <sub>PP</sub>	1350	W	8/20µs (Note 7)
ESD Protection—Contact Discharge	Vesd_contact	±30	kV	Standard IEC61000-4-2
ESD Protection—Air Discharge	V <sub>ESD_AIR</sub>	±30	kV	Standard IEC61000-4-2

# **Thermal Characteristics**

Characteristic	Symbol	Value	Unit
Power Dissipation (Note 5)	PD	300	mW
Thermal Resistance, Junction to Ambient, $T_A = +25^{\circ}C$	R <sub>OJA</sub>	417	°C/W
Operating and Storage Temperature Range	T <sub>J</sub> , T <sub>STG</sub>	-55 to +150	٥C

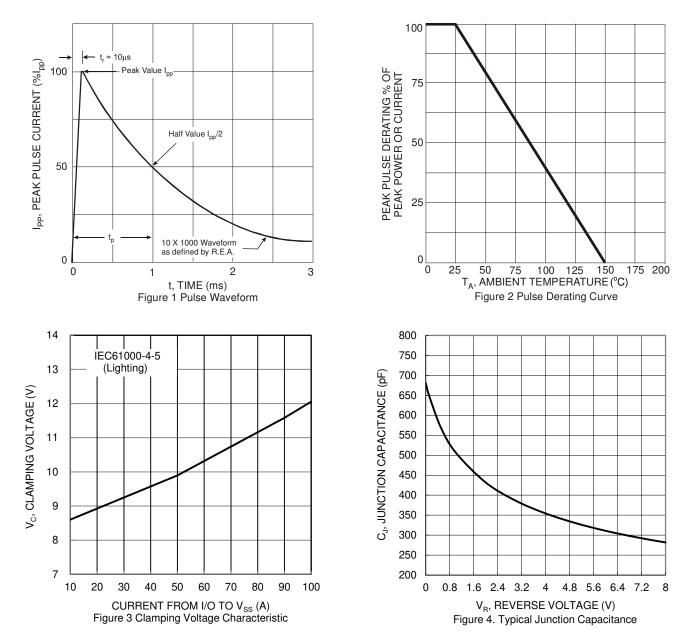
# Electrical Characteristics (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition
Reverse Standoff Voltage	V <sub>RWM</sub>		_	8.0	V	—
Channel Leakage Current (Note 6)	IR		_	1	μA	V <sub>R</sub> = 8.0V
Reverse Breakdown Voltage	V <sub>BR</sub>	8.2	—	9.0	V	I <sub>R</sub> = 1mA
			_	9.5	V	I <sub>PP</sub> = 10A, t <sub>P</sub> = 8/20µs
Clamping Voltage, Positive Transients (Note 7)	Vc	—	—	11	V	I <sub>PP</sub> = 50A, t <sub>P</sub> = 8/20µs
			—	13.5	V	I <sub>PP</sub> = 100A, t <sub>P</sub> = 8/20μs
Channel Input Capacitance (Note 8)	Ст	_	700	_	pF	V <sub>R</sub> = 0V, f = 1MHz, Any I/O to GND

Notes: 5. Device mounted on FR-4 PCB pad layout (2oz copper) as shown on Diodes Incorporated's suggested pad layout, which can be found on our website at http://www.diodes.com/package-outlines.html.
6. Short duration pulse test used to minimize self-heating effect.
7. Clamping voltage value is based on an 8 × 20µs peak pulse current (I<sub>PP</sub>) waveform.
8. Measured from any I/O to GND.



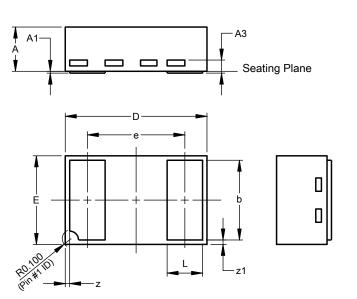
# D8V0H1U2LP1610





# **Package Outline Dimensions**

Please see http://www.diodes.com/package-outlines.html for the latest version.



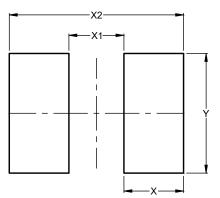
U-DFN1610-2								
(Type B)								
Dim	Min	Max	Тур					
Α	0.45	0.55	0.50					
A1	0.00	0.05	0.015					
A3	-	-	0.127					
b	0.85	0.95	0.90					
D	1.55	1.65	1.60					
Е	0.95	1.05	1.00					
е	-	-	1.10					
L	0.35	0.45	0.40					
z	0.050 REF							
z1	0.050 REF							
Ali d	imens	ions in	mm					

# Suggested Pad Layout

Please see http://www.diodes.com/package-outlines.html for the latest version.

#### U-DFN1610-2 (Type B)

U-DFN1610-2 (Type B)



Dimensions	Value (in mm)
Х	0.650
X1	0.600
X2	1.900
Y	1.300



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